

Aluminium oxide slices are used for insulated assembly of semiconductors for high voltage ranges. Despite the high dielectric strength, good heat transfer, from the semiconductor to the heat sink is available.

General values:Colour: white

Dielectric strength: approx. 10 KV / mm

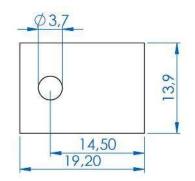
Dielectric loss factor at 1 MHz:10⁴ Dielectric constant at 1 MHz: 9.1

Specific resistance: 10^4 Ohm x cm Density: 3.9 gm^3 purity 96 % approx. 0.5 K/W

The following pages contain standard sections for prevalent semiconductor shapes. We are be pleased to cut customised aluminium oxide slices for you based on your drawing.

AO 475



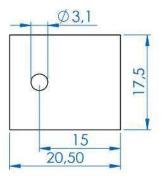


For Casing: TO 220

Thermal Conductivity: [W/mK]: 25 Thickness: [mm]: 1.6

AO 472





For Casing: TO 218, TOP 3

Thermal Conductivity: [W/mK]: 25

Thickness: [mm]: 1.6



AO 479



2 14 18

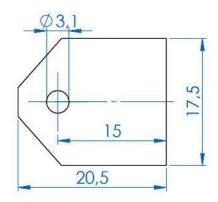
For Casing: TO 220

Thermal Conductivity: [W/mK]: 25

Thickness: [mm]: 1.5

AO 471





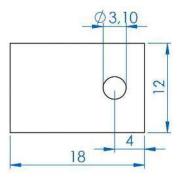
For Casing: TO 218, TOP 3

Thermal Conductivity: [W/mK]: 25

Thickness: [mm]: 1.5

AO 474





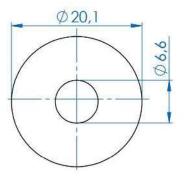
For Casing: TO 220

Thermal Conductivity: [W/mK]: 25

Thickness: [mm]: 1.5

AO 478





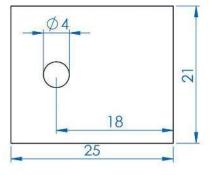
For Casing: **DO 5 (Diode)**

Thermal Conductivity: [W/mK]: 25

Thickness: [mm]: 1.6

AO 480





For Casing: TO 218, TOP 3

Thermal Conductivity: [W/mK]: 25

Thickness: [mm]: 3